

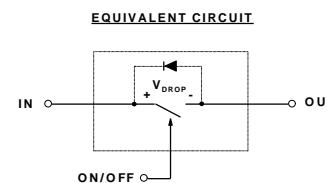
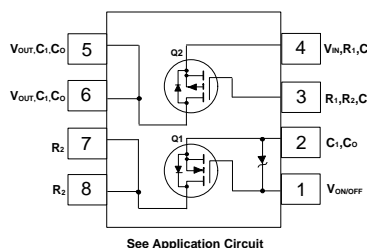
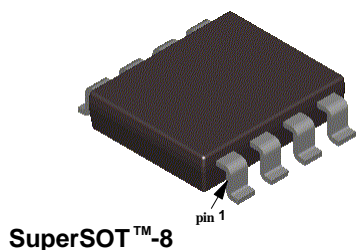
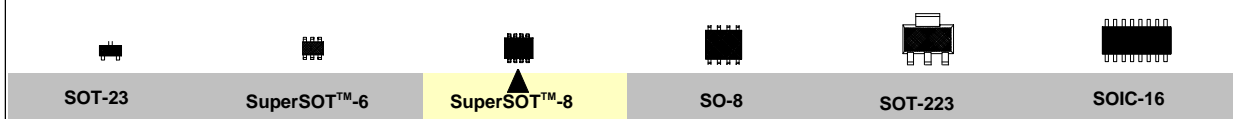
## FDR8321L P-Channel MOSFET With Gate Driver For Load Switch Application

### General Description

This device is designed for configuration as a load switch and is particularly suited for Power Management in portable battery powered electronic equipment. Designed to operate from 2.5V to 8V input and supply up to 2.9A. The device features a small N-Channel MOSFET (Q1) together with a large P-Channel power MOSFET (Q2) in a single SuperSOT™-8 package.

### Features

- $V_{\text{DROP}} = 0.2\text{V}$  @  $V_{\text{IN}} = 5\text{V}$ ,  $I_{\text{L}} = 2.9\text{A}$ .  $R_{\text{DS(ON)}} = 0.070\ \Omega$   
 $V_{\text{DROP}} = 0.2\text{V}$  @  $V_{\text{IN}} = 2.5\text{V}$ ,  $I_{\text{L}} = 2\text{A}$ .  $R_{\text{DS(ON)}} = 0.105\ \Omega$ .
- $V_{\text{ON/OFF}}$  Zener protection for ESD ruggedness (>6KV Human Body Model).
- High density cell design for extremely low on-resistance.



### Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol                         | Parameter  | FDR8321L   | Units            |
|--------------------------------|--|------------|------------------|
| $V_{\text{IN}}$                | Input Voltage Range  | 2.5 - 8    | V                |
| $V_{\text{ON/OFF}}$            | On/Off Voltage Range   | 1.5 - 8    | V                |
| $I_{\text{L}}$                 | Load Current @ $V_{\text{DROP}} = 0.2\text{V}$ - Continuous (Note 1)<br>- Pulsed | 2.9        | A                |
|                                |  | 10         |                  |
| $P_{\text{D}}$                 | Maximum Power Dissipation (Note 2)   | 0.8        | W                |
| $T_{\text{J}}, T_{\text{STG}}$ | Operating and Storage Temperature Range  | -55 to 150 | $^\circ\text{C}$ |

### THERMAL CHARACTERISTICS

|                       |  |     |                    |
|-----------------------|--|-----|--------------------|
| $R_{\theta\text{JA}}$ | Thermal Resistance, Junction-to-Ambient (Note 2) | 156 | $^\circ\text{C/W}$ |
| $R_{\theta\text{JC}}$ | Thermal Resistance, Junction-to-Case (Note 2)    | 40  | $^\circ\text{C/W}$ |

## Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

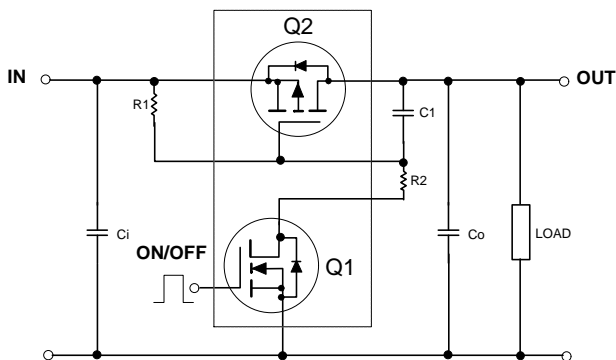
| Symbol                             | Parameter  | Conditions  | Min | Typ   | Max   | Units |
|------------------------------------|--|---|-----|-------|-------|-------|
| <b>OFF CHARACTERISTICS</b>         |  |   |     |       |       |       |
| I <sub>FL</sub>                    | Forward Leakage Current                            | V <sub>IN</sub> = 5 V, V <sub>ON/OFF</sub> = 0 V                                |     |       | 1     | μA    |
| <b>ON CHARACTERISTICS</b> (Note 3) |  |   |     |       |       |       |
| V <sub>DROP</sub>                  | Conduction Voltage Drop                            | V <sub>IN</sub> = 5 V, V <sub>ON/OFF</sub> = 3.3 V, I <sub>L</sub> = 2.9 A      |     | 0.185 | 0.2   | V     |
|                                    |  | V <sub>IN</sub> = 2.5 V, V <sub>ON/OFF</sub> = 3.3 V, I <sub>L</sub> = 2 A      |     | 0.18  | 0.2   |       |
| R <sub>DS(ON)</sub>                | Q <sub>2</sub> - Static Drain-Source On-Resistance | V <sub>GS</sub> = -5 V, I <sub>D</sub> = -2.9 A                                 |     | 0.06  | 0.07  | Ω     |
|                                    |  | V <sub>GS</sub> = -2.5 V, I <sub>D</sub> = -2 A                                 |     | 0.09  | 0.105 |       |
| I <sub>L</sub>                     | Load Current                                       | V <sub>DROP</sub> = 0.2 V, V <sub>IN</sub> = 5 V, V <sub>ON/OFF</sub> = 3.3 V   | 2.9 |       |       | A     |
|                                    |  | V <sub>DROP</sub> = 0.2 V, V <sub>IN</sub> = 2.5 V, V <sub>ON/OFF</sub> = 3.3 V | 2   |       |       |       |

### Notes:

- V<sub>IN</sub>=5V, V<sub>ON/OFF</sub>=8V, V<sub>DROP</sub>=0.2V, T<sub>A</sub>=25°C
- R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design while R<sub>θCA</sub> is determined by the user's board design. R<sub>θJA</sub> typical =156°C/W when mounted on a minimum 0.0025 in<sup>2</sup> pad on FR-4.
- Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

## FDR8321L Load Switch Application

### APPLICATION CIRCUIT



### External Component Recommendation

First select R2, 100 - 1kΩ, for Slew Rate control.

C1 ≤ 1000pF can be added in addition to R2 for further In-rush current control.

Then select R1 such that R1/R2 ratio maintains between 10 - 100. R1 is required to turn Q2 off.

For SPICE simulation, users can download a "FDR8321L.MOD" Spice model from Fairchild Web Site at [www.fairchildsemi.com](http://www.fairchildsemi.com)

**Typical Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

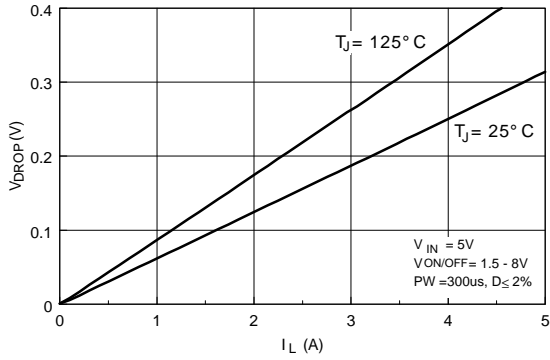


Figure 1. Conduction Voltage Drop versus Load Current at Input Voltage 5V.

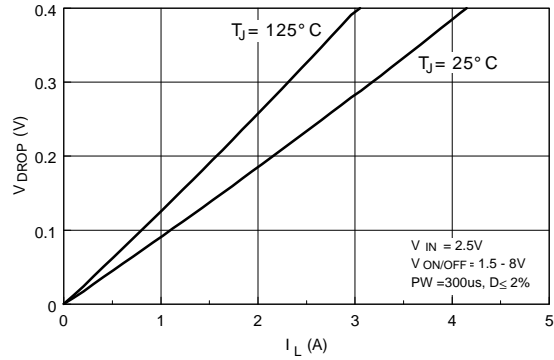


Figure 2. Conduction Voltage Drop versus Load Current at Input Voltage 2.5V.

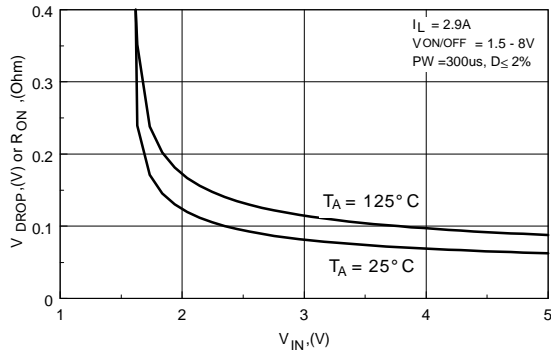


Figure 3. Conduction Voltage Drop versus input Voltage at Load Current 2.9A.

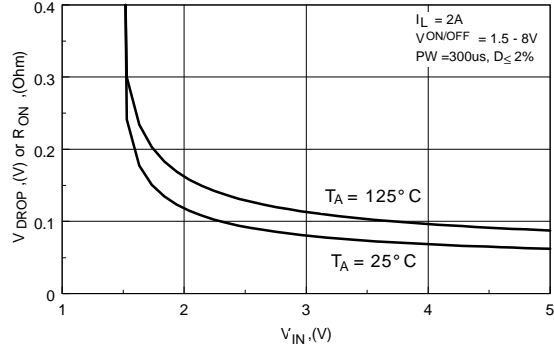


Figure 4. Conduction Voltage Drop versus Input Voltage at Load Current 2A.

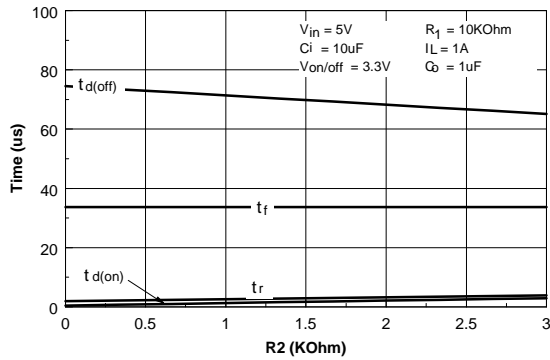


Figure 5. Switching Variation with  $R_2$  at  $V_{in} = 5\text{V}$  and  $R_1 = 10\text{K}\Omega$ .

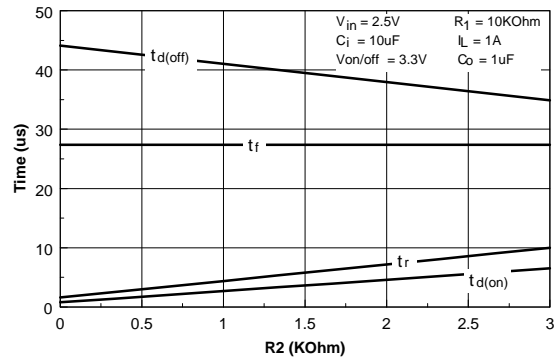
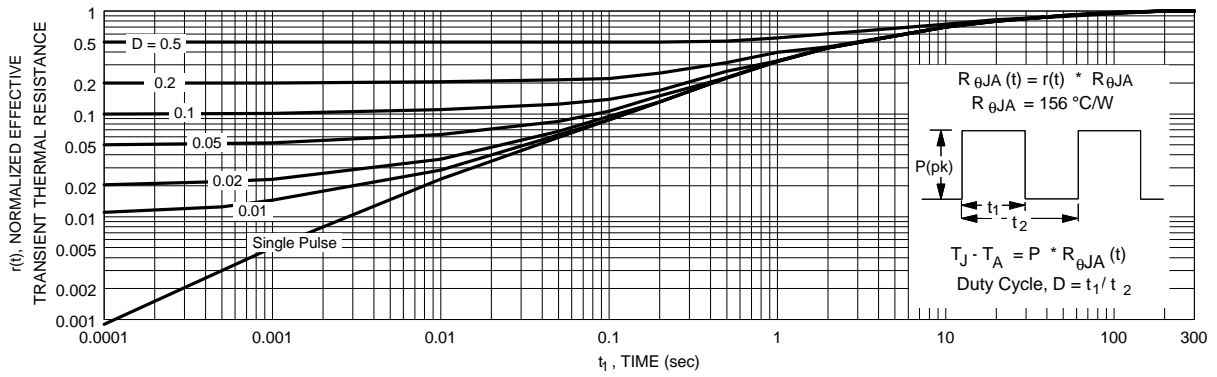


Figure 6. Switching Variation with  $R_2$  at  $V_{in} = 2.5\text{V}$  and  $R_1 = 10\text{K}\Omega$ .

**Typical Electrical Characteristics** ( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted )



**Figure 7. Transient Thermal Response Curve.**

Thermal characterization performed on the conditions described in Note 2.

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| E <sup>2</sup> CMOS™ | MICROWIRE™          | SuperSOT™-6         |      |
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